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To Examiner: Jack S.J. Chen	Total Pages Sent: 8
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Facsimile Number: (703) 872-9306	Transmission Date: August 3, 2004

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

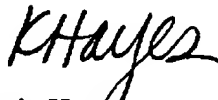
Applicant: Tews, *et al.* Docket No.: 00P9031US
Serial No: 09/714,356 Art Unit: 2813
Date Filed: November 16, 2000
TITLE: Nitrogen Implantation Using a Shadow Effect to Control Gate Oxide Thickness
in DRAM Semiconductor

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- Certification of Facsimile Transmission (1 page)
- Response (7 pages)

Respectfully submitted,



Kristin Hayes
Legal Assistant

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OFFICIAL**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**Applicants: Tews, *et al.*

Docket No.: 00P9031US

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Art Unit: 2813

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Filed: November 16, 2000

Examiner: Chen, Jack S.J.

For: Nitrogen Implantation Using a Shadow Effect to Control Gate Oxide Thickness in
DRAM SemiconductorCommissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450**RESPONSE**

Dear Sir:

Applicant has received and reviewed the Office Action mailed on July 6, 2004 and respectfully requests reconsideration based on the following remarks.

00P9031US

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